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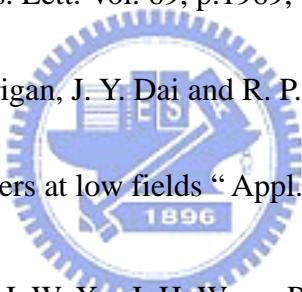
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(92 年 9 月～94 年 7 月)

論文題目：藉由密度控制以提高真空微電子用之奈米碳管之場發射特性

Improvement of the Field Emission Characteristics of the

Carbon Nanotubes via the Density Control for Micro Electronics

Applications

Publication Lists

International and Local Conferences:

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專利申請

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